

Lab 4 Report

Ty Davis

October 18, 2023

1 Introduction

In this lab we are only analyzing one circuit. This is the circuit shown in Figure 1 and it features the 2N2700 MOSFET device known as a 2N2700. In this lab we aren't using that device as it is intended to be used, but rather we are going to be putting the device under unusual circumstances. This ended up resulting in some irregular patterns in our measurements as you'll see later in the lab report.

A MOSFET device is one that allow us to effectively "flip" a switch electronically by supplying a voltage into the device which determines if current should or shouldn't flow through the other portion of the device.

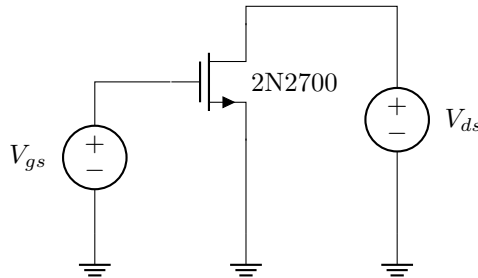


Figure 1: Circuit Featuring an NMOS IV Component

2 Sweeping the V_{gs}

For the first portion of the lab we set up the circuit as shown in Figure 1, and we kept the value of V_{ds} constant at 5 V while sweeping the value of V_{gs} . By doing this we are analyzing at what value V_{gs} does the MOSFET "turn on" and allow current to flow through the other portion of the device. As you can see from Figure 2, the current flowing through the device just started to flow at about $V_{gs} = 2.2$ V and made a significant jump at $v_{gs} = 2.3$ V. Essentially, when the voltage reached 2.3 volts you could consider the transistor as "turned on" and significant current was then flowing through the circuit.

These findings match our simulation from Multisim as shown in Figure 3.

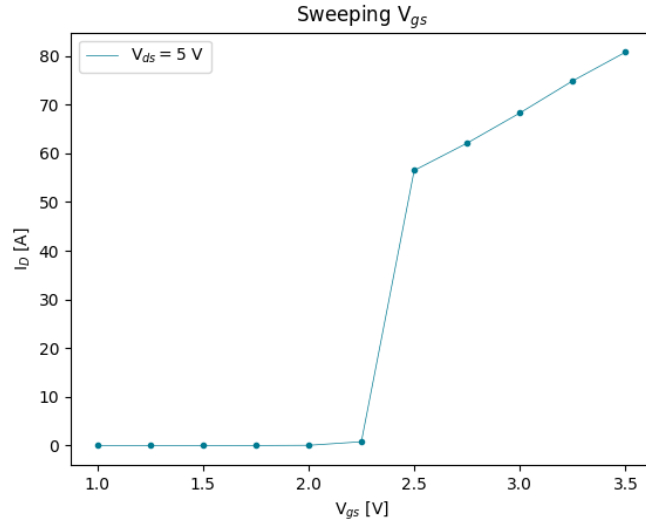


Figure 2: Results from Sweeping the V_{gs} Value

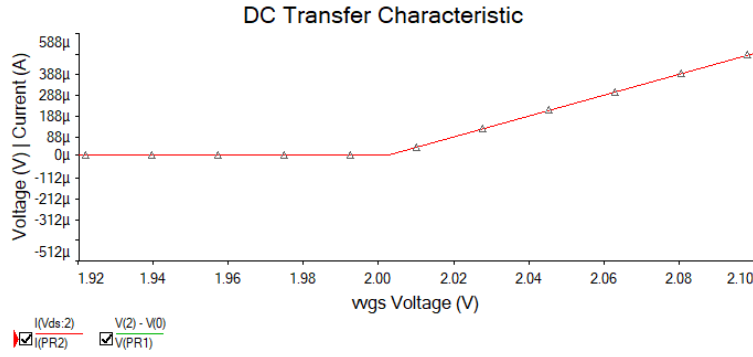


Figure 3: Simulation of Current Starting to Flow

3 Sweeping the V_{ds}

In this second portion of the lab we were tasked with sweeping the value of the V_{ds} voltage which is where the current that we are measuring is coming from. The point of this is to see how different voltage values of V_{gs} will affect the current output of the transistor. As you can see in Figure 4, the value of V_{gs} will change the current throughput of the transistor for the different values of V_{ds} .

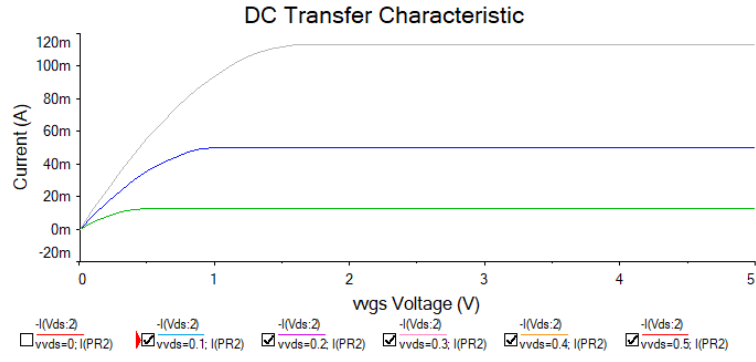


Figure 4: Currents Simulated for Various V_{gs} Values

4 Conclusion